



NHD-C0216CZ-FSW-FBW-3V3

COG (Chip-on-Glass) Liquid Crystal Display Module

NHD- Newhaven Display

CO216- COG, 2 Lines x 16 Characters

CZ- Model

F- Transflective

SW- Side White LED Backlight

F- FSTN Positive.
B- 6:00 Optimal View
W- Wide Temperature
3V3- 3.3V LCD, 3V Backlight

RoHS Compliant

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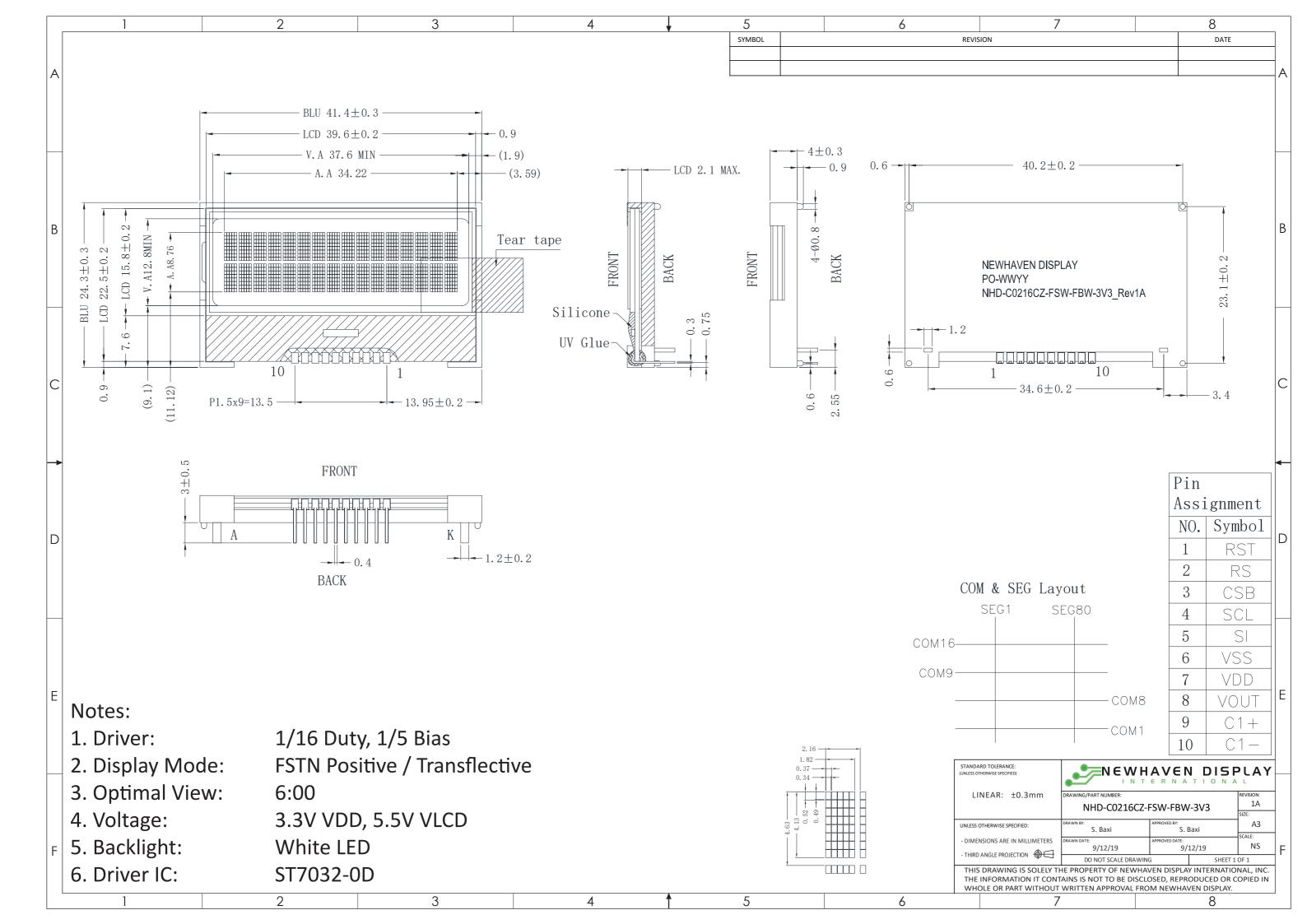
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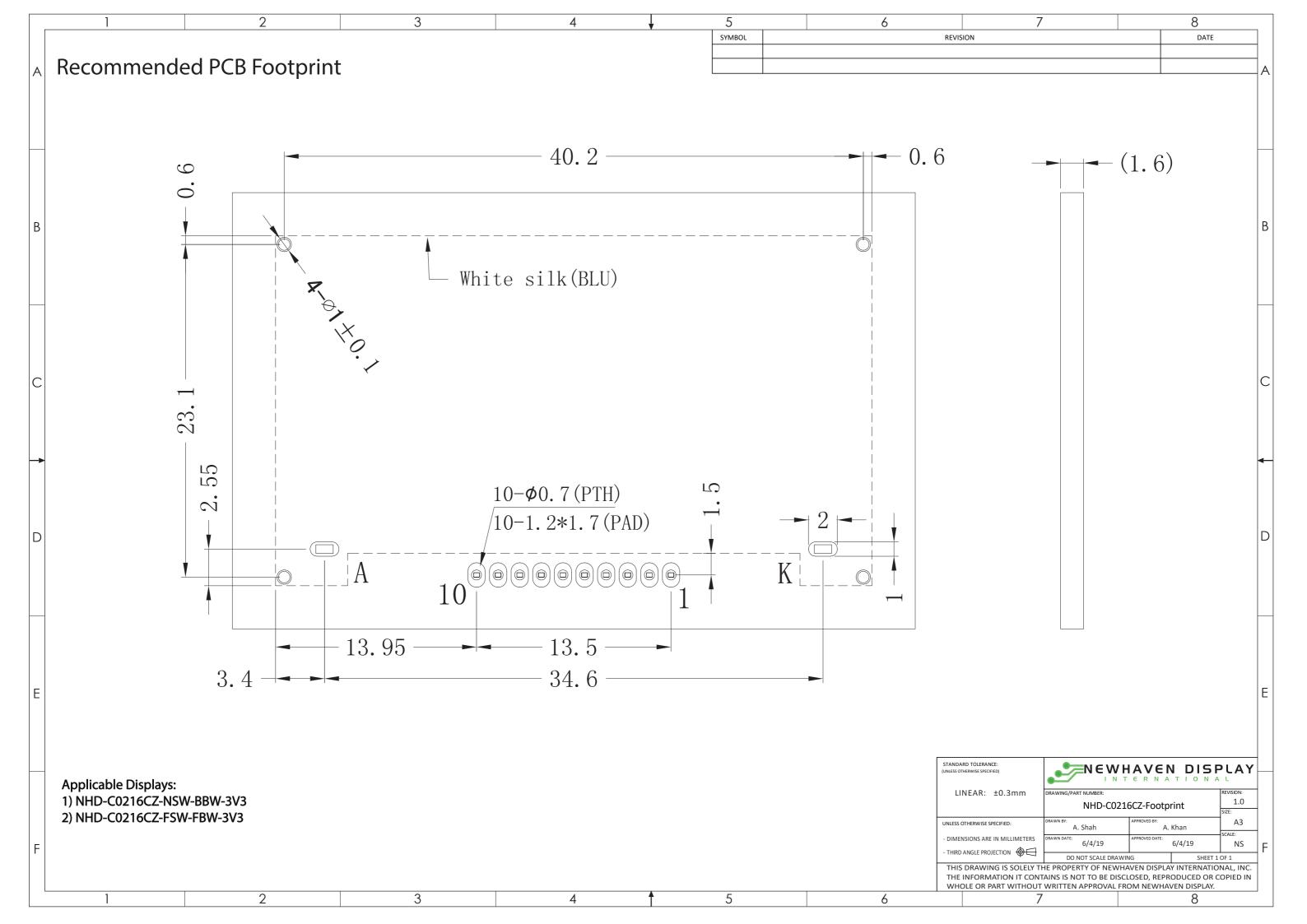
Document Revision History

Revision	Date	Description	Changed by
0	11/11/2008	Initial Release	-
1	8/26/2009	User guide reformat	BE
2	10/9/2009	Updated Electrical Characteristics	MC
3	10/22/2009	Font Table Revision	BE
4	10/27/2009	Updated the Block Diagram	MC
5	11/19/2009	Updated backlight supply current	MC
6	12/18/2009	Pin description updated	BE
7	3/2/2012	Interface information updated	AK
8	7/22/2013	Electrical characteristics updated	ML
9	12/10/2014	Recommended connector information updated	AK
10	10/20/16	Mechanical Drawing, Electrical & Optical Char. Updated	SB
11	1/20/17	P/N Printed on Back of Display, Electrical Char. Updated	SB
12	8/24/18	Supply Current Updated	SB
13	11/15/18	Updated Font Table for CGRAM	TM
14	6/24/19	Added PCB Footprint Drawing	AS
15	9/12/19	Supply Current Updated	SB

Functions and Features

- 2 lines x 16 characters
- Built-in controller (ST7032)
- 5x8 dots with cursor
- 4-line serial interface
- 1/16 duty, 1/5 bias

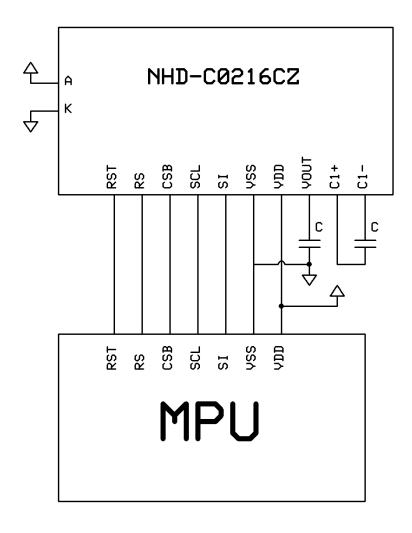




Pin Description and Wiring Diagram

Pin No.	Symbol	External Connection	Function Description
1	RST	MPU	Active LOW Reset Signal
2	RS	MPU	Register Select Signal. RS=0: instruction; RS=1: data
3	CSB	MPU	Active LOW Chip Select signal
4	SCL	MPU	Serial Clock
5	SI	MPU	Serial Input data
6	V_{SS}		Ground
7	V_{DD}	Power Supply	Power supply for logic for LCD (3.3V).
8	Vout		DC/DC voltage converter. Connect to 1uF capacitor to V _{DD} or V _{SS}
9	C1+	-	Voltage booster circuit. Connect to 0.47µF-2.2µF cap to PIN10.
10	C1-	-	Voltage booster circuit. Connect to 0.47μF-2.2μF cap to PIN9.
Α	LED+	Power Supply	Backlight Anode (3.0V)
K	LED-	Power Supply	Backlight Cathode (Ground)

Recommended LCD connector: LCD pins should be soldered directly onto thru-hole connection on PCB **Backlight connector:** Backlight pins should be soldered directly onto thru-hole connection on PCB **Recommended Breakout Board:** NHD-PCB0216CZ



Electrical Characteristics

Item	Symbol	Condition	Min.	Тур.	Max.	Unit
Operating Temperature Range	T _{OP}	Absolute Max	-20	-	+70	°C
Storage Temperature Range	T _{ST}	Absolute Max	-30	-	+80	°C
Supply Voltage	V_{DD}	-	3.0	3.3	3.6	V
Supply Current	I _{DD}	$V_{DD} = 3.3V$	40	170	300	μΑ
Supply for LCD (contrast)	V_{LCD}	$T_{OP} = 25^{\circ}C$	5.2	5.5	5.8	V
"H" Level input	V _{IH}	-	1.9	-	V_{DD}	V
"L" Level input	V _{IL}	-	Vss	-	0.8	V
"H" Level output	Voh	-	0.75 * V _{DD}	-	V_{DD}	V
"L" Level output	Vol	-	Vss	-	0.8	V
Backlight Supply Voltage	V _{LED}	-	3.0	3.1	3.2	V
Backlight Supply Current	I _{LED}	V _{LED} = 3.1V	10	30	36	mA

Optical Characteristics

	Ite	em	Symbol	Condition	Min.	Тур.	Max.	Unit
Outime	Тор		φΥ+		ı	20	1	0
Optimal Viewing	Bott	tom	φΥ-	CR ≥ 2	-	40	-	0
Angles	Left		θХ-	CR ≥ 2	-	40	-	0
Aligies	Righ	nt	θХ+		-	40	-	0
Contrast Rat	io		CR	-	2	4	-	-
Dosmonso T	ima	Rise	T_R	T - 35°C	ı	200	300	ms
Response T	ime	Fall	T _F	$T_{OP} = 25^{\circ}C$	ı	250	350	ms

Controller Information

Built-in ST7032 Controller.

Please download specification at http://www.newhavendisplay.com/app notes/ST7032.pdf

DDRAM Address

1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16
00	01	02	03	04	05	06	07	08	09	0A	OB	0C	0D	0E	OF
40	41	42	43	44	45	46	47	48	49	4A	4B	4C	4D	4E	4F

Table of Commands

				Ins	tructi	on co	ode					Instructi	on Executi	on Time
Instruction	RS	R/W	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0	Description	OSC= 380kHz	OSC = 540kHz	OSC= 700kHz
Clear Display	0	0	0	0	0	0	0	0	0	1	Write "20H" to DDRAM and set DDRAM address to "00H" from AC	1.08 ms	0.76 ms	0.59 ms
Return Home	0	0	0	0	0	0	0	0	1	Х	Set DDRAM Address to "00H" from AC and return cursor to its original position if shifted. The contents of DDRAM are not changed.	1.08 ms	0.76 ms	0.59 ms
Entry Mode Set	0	0	0	0	0	0	0	1	I/D	S	Sets cursor move direction and specifies display shift. These parameters are performed during data write and read.	26.3 μs	18.5 μs	14.3 μs
Display ON/OFF	0	0	0	0	0	0	1	D	С	В	D=1: Entire display on C=1: Cursor on B=1: Blinking cursor on	26.3 μs	18.5 μs	14.3 μs
Function set	0	0	0	0	1	DL	N	DH	IS2	IS1	DL: Interface data is 8/4 bits N: Number of lines is 2/1 DH: Double Height Font IS 2~1: Instruction Table Select	26.3 μs	18.5 μs	14.3 μs
Set DDRAM Address	0	0	1	AC6	AC5	AC4	AC3	AC2	AC1	AC0	Set DDRAM address in address counter.	26.3 μs	18.5 μs	14.3 μs
Read busy Flag and Address	0	1	BF	AC6	AC5	AC4	AC3	AC2	AC1	AC0	Whether during internal operation or not can be known by reading BF. The contents of address counter can also be read.	0	0	0
Write data To Address	1	0	D7	D6	D5	D4	D3	D2	D1	D0	Write data into internal RAM (DDRAM/CGRAM).	26.3 μs	18.5 μs	14.3 μs
Read data From RAM	1	1	D7	D6	D5	D4	D3	D2	D1	D0	Read data from internal RAM (DDRAM/CGRAM/ICONRAM).	26.3 μs	18.5 μs	14.3 μs

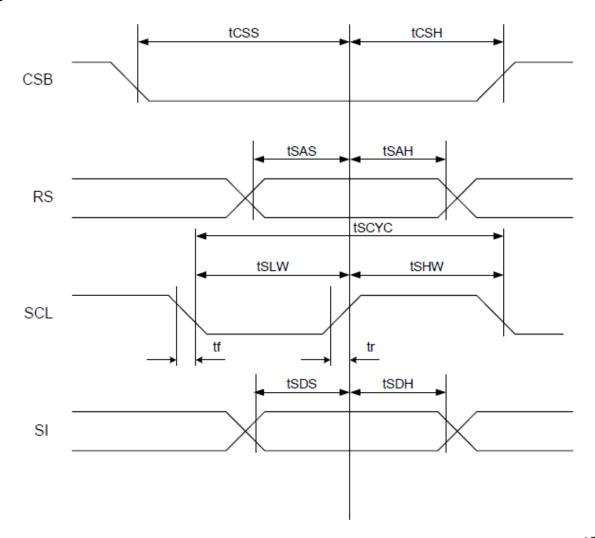
	Instruction Table 0 (IS[2:1] = [0,0]))													
Cursor or Display shift	0	0	0	0	0	1	S/C	R/L	х	Х	Sets cursor moving and display shift control bit, and the direction without changing DDRAM data.	26.3 μs	18.5 μs	14.3 μs
Set CGRAM	0	0	0	1	AC5	AC4	AC3	AC2	AC1	AC0	Set CGRAM address in address counter	26.3 μs	18.5 μs	14.3 μs

						nstru	ction 1	Table 1	(IS[2:	1] = [0	0,1]))			
Internal OSC Frequency	0	0	0	0	0	1	BS	F2	F1	F0	BS = 1 : 1/4 bias BS= 0 : 1/5 bias F2~0 : Adjust internal OSC frequency for FR frequency	26.3 μs	18.5 μs	14.3 μs
Set ICON Address	0	0	0	1	0	0	AC3	AC2	AC1	AC0	Set ICON address in address counter	26.3 μs	18.5 μs	14.3 μs
Power/ICON control/Cont rast set	0	0	0	1	0	1	Ion	Bon	C5	C4	Ion: ICON display on/off Bon: Set booster circuit on/off C5,C4: Contrast set for internal follower mode	26.3 μs	18.5 μs	14.3 μs
Follower Control	0	0	0	1	1	0	Fon	Rab 2	Rab 1	Rab 0	Fon: Set follower circuit on/off Rab 2~0: select follower amplified ratio	26.3 μs	18.5 μs	14.3 μs
Contrast Set	0	0	0	1	1	1	C3	C2	C1	C0	Contrast set for internal follower mode.	26.3 μs	18.5 μs	14.3 μs

					I	nstruc	tion T	able 2	((IS[2	:1] = [(0,0]))			
Double Height Position Select	0	0	0	0	0	1	UD	х	Х	х	UD: Double height position Select	26.3 μs	18.5 μs	14.3 μs
Reserved	0	0	0	1	Χ	Χ	Х	Х	Χ	Χ	Do not use (Reserved for Test)	26.3 μs	18.5 μs	14.3 µs

^{*}Instruction Table 3 (IS[2,1] = [1,1]): Do not use (Reserved for Test)

Timing Characteristics



(Ta = 25°C)

Item	Signal	Symbol	Condition		7 to 4.5V ting		5 to 5.5V ting	Units
Kem	Oigilai	Cymbol		Min.	Max.	Min.	Max.	Simi3
Serial Clock Period		tscyc		200	-	100	-	
SCL "H" pulse width	SCL	tsHW	_	20	-	20	-	ns
SCL "L" pulse width		tsLw		160	-	120	-	
SCL Rise/Fall time	SCL	tr,tf	_	-	20	-	20	ns
Address setup time	RS	tsas		10	-	10	-	ne
Address hold time	KS	tsah		250	-	150	-	ns
Data setup time	SI	tsps		10	-	10	-	ns
Data hold time	31	tsdh		10	-	20	-	115
CS-SCL time	CS	tcss		20	-	20	-	ns
CS-SCL time	CS	tсsн		350	-	200	-	115

Built-In Font Table

ST7032-0D (ITO option OPR1=0, OPR2=0)

67-64 63-60	0000	0001	0010	0011	0100	0101	0110	0111	1000	1001	1010	1011	1100	1101	1110	1111
0000														***	***	
0001	R															
0010	Replaced															
0011	d By C							****								
0100	GRAM															
0101	l Pattern															
0110	m															
0111																
1000																
1001	R															
1010	Replaced															
1011	ВуС															
1100	GRAM															***
1101	1 Pattern															
1110] = [
1111																

Example Initialization Program

```
void init()
//initialize the LCD
 P3 = 1;
P1 = 1;
RST = 0;
                                           //RESET
delay(2);
RST = 1;
                                           //end reset
delay(20);
Writecom(0x30);
                                            //wake up
delay(2);
Call writecom(0x30);
                                            //wake up
Call writecom(0x30);
                                            //wake up
Call writecom(0x39);
                                            //function set
Call writecom(0x14);
                                            //internal osc frequency
Call writecom(0x56);
                                            //power control
                                            //follower control
Call writecom(0x6D);
Call writecom(0x70);
                                             //contrast
Call writecom(0x0C);
                                             //display on
Call writecom(0x06);
                                             //entry mode
Call writecom(0x01);
                                             //clear
delay(10);
void writecom(int d)
CS = 0:
                                             //CS
RS = 0:
                                             //A0 = Command
for(serialcounter = 1; serialcounter <= 8; serialcounter++) //send 8 bits
 if((d\&0x80)==0x80)
                                             //get only the MSB
                                             //if 1, then SI=1
        SI=1;
 else
        SI=0:
                                             //if 0, then SI=0
 d=(d<<1);
                                             //shift data byte left
 SCL = 0;
 SCL = 1;
 SCL = 0;
                                              //SCL
CS = 1;
void writedata(int d)
CS = 0;
                                             //CS
RS = 1;
                                              //A0 = Data
for(serialcounter = 1; serialcounter <= 8; serialcounter++) //send 8 bits
 if((d\&0x80)==0x80)
                                              //get only the MSB
        SI=1;
                                             //if 1, then SI=1
 else
        SI=0:
                                             //if 0, then SI=0
 d=(d<<1);
                                             //shift data byte left
 SCL = 0;
 SCL = 1;
 SCL = 0:
                                             //SCL
CS = 1;
```

Quality Information

Test Item	Content of Test	Test Condition	Note
High Temperature storage	Endurance test applying the high storage temperature for a long time.	+80°C , 96hrs	2
Low Temperature storage	Endurance test applying the low storage temperature for a long time.	-30°C , 96hrs	1,2
High Temperature Operation	Endurance test applying the electric stress (voltage & current) and the high thermal stress for a long time.	+70°C, 96hrs	2
Low Temperature Operation	Endurance test applying the electric stress (voltage & current) and the low thermal stress for a long time.	-20°C , 96hrs	1,2
High Temperature / Humidity Operation	Endurance test applying the electric stress (voltage & current) and the high thermal with high humidity stress for a long time.	+40°C, 90% RH, 96hrs	1,2
Thermal Shock resistance	Endurance test applying the electric stress (voltage & current) during a cycle of low and high thermal stress.	-20°C,60min -> 25°C,5min -> 70°C,60min = 1 cycle 20 cycles	
Vibration test	Endurance test applying vibration to simulate transportation and use.	10-55Hz, 5G Acceleration. 60 sec in each of 3 directions X,Y,Z for 30 minutes	3
Static electricity test	Endurance test applying electric static discharge.	VS=8kV, RS=330 Ω , CS=150pF five times	

Note 1: No condensation to be observed.

Note 2: Conducted after 4 hours of storage at 25°C, 0%RH.

Note 3: Test performed on product itself, not inside a container.

Precautions for using LCDs/LCMs

See Precautions at www.newhavendisplay.com/specs/precautions.pdf

Warranty Information and Terms & Conditions

http://www.newhavendisplay.com/index.php?main_page=terms